

**H11G1X, H11G2X, H11G3X**  
**H11G1, H11G2, H11G3**



**HIGH VOLTAGE DARLINGTON  
 OUTPUT OPTICALLY COUPLED  
 ISOLATOR**

**APPROVALS**

- UL recognised, File No. E91231

**'X' SPECIFICATION APPROVALS**

- VDE 0884 in 2 available lead forms : -  
 - STD  
 - G form

**DESCRIPTION**

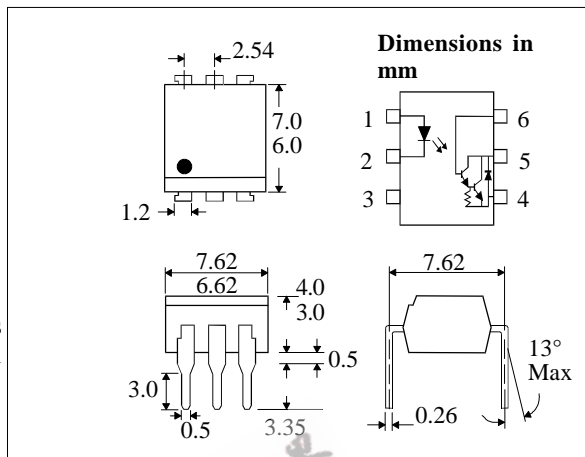
The H11G\_ series are optically coupled isolators consisting of an infrared light emitting diode and a high voltage NPN silicon photo darlington which has an integral base-emitter resistor to optimise switching speed and elevated temperature characteristics in a standard 6pin dual in line plastic package.

**FEATURES**

- Options :-  
 10mm lead spread - add G after part no.  
 Surface mount - add SM after part no.  
 Tape&reel - add SMT&R after part no.
- High Isolation Voltage (5.3kV<sub>RMS</sub>, 7.5kV<sub>PK</sub>)
- High Current Transfer Ratio (1000% min)
- High BV<sub>CEO</sub> (H11G1 - 100V min.)
- Low collector dark current :-  
 100nA max. at 80V V<sub>CE</sub>
- Low input current 1mA I<sub>F</sub>

**APPLICATIONS**

- Modems
- Copiers, facsimiles
- Numerical control machines
- Signal transmission between systems of different potentials and impedances



**ABSOLUTE MAXIMUM RATINGS  
 (25°C unless otherwise specified)**

Storage Temperature	-55°C to + 150°C
Operating Temperature	-55°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

**INPUT DIODE**

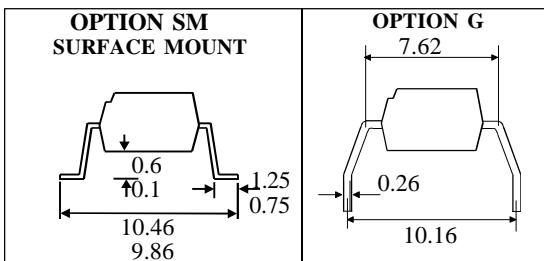
Forward Current	60mA
Peak Forward Current (1µs pulse, 300pps)	3A
Reverse Voltage	3V
Power Dissipation	100mW

**OUTPUT TRANSISTOR**

Collector-emitter Voltage BV <sub>CEO</sub> H11G3, H11G2, H11G1	55, 80, 100V
Collector-base Voltage BV <sub>CBO</sub> H11G3, H11G2, H11G1	55, 80, 100V
Emitter-base Voltage BV <sub>ECO</sub>	6V
Power Dissipation	200mW

**POWER DISSIPATION**

Total Power Dissipation	260mW
-------------------------	-------



**ISOCOMCOMPONENTSLTD**  
 Unit 25B, Park View Road West,  
 Park View Industrial Estate, Brenda Road  
 Hartlepool, TS25 1YD England Tel: (01429)863609  
 Fax: (01429) 863581 e-mail sales@isocom.co.uk  
<http://www.isocom.com>

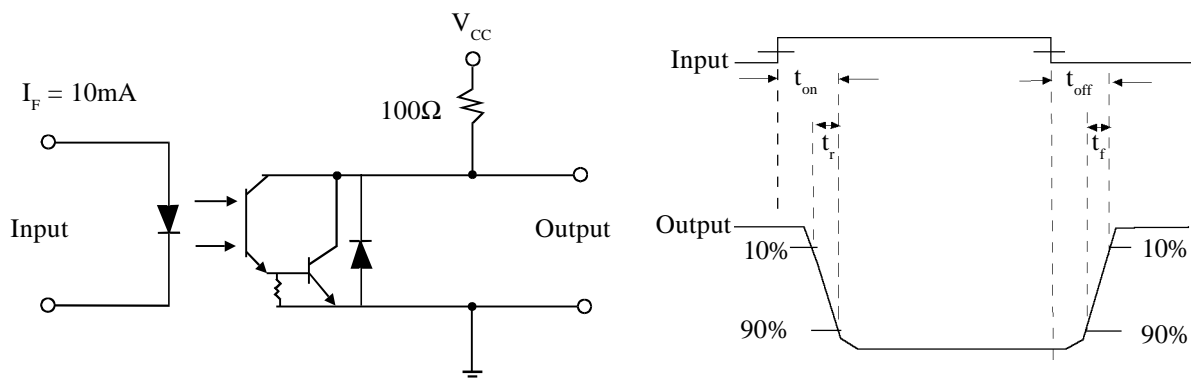
**ELECTRICAL CHARACTERISTICS (  $T_A = 25^\circ\text{C}$  Unless otherwise noted )**

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage ( $V_F$ )		1.2	1.5	V	$I_F = 10\text{mA}$
	Reverse Voltage ( $V_R$ )	3			V	$I_R = 10\mu\text{A}$
	Reverse Current ( $I_R$ )			10	$\mu\text{A}$	$V_R = 6\text{V}$
Output	Collector-emitter Breakdown ( $BV_{CEO}$ )				V	$I_C = 1\text{mA}$
	H11G1	100			V	$I_C = 1\text{mA}$
	H11G2	80			V	$I_C = 1\text{mA}$
	H11G3	55			V	$I_C = 1\text{mA}$
	Collector-base Breakdown ( $BV_{CBO}$ )				V	$I_C = 100\mu\text{A}$
	H11G1	100			V	$I_C = 100\mu\text{A}$
	H11G2	80			V	$I_C = 100\mu\text{A}$
	H11G3	55			V	$I_C = 100\mu\text{A}$
	Emitter-base Breakdown ( $BV_{EBO}$ )	6			V	$I_E = 0.1\text{mA}$
	Collector-emitter Dark Current ( $I_{CEO}$ )				nA	$V_{CE} = 80\text{V}$
H11G1			100	nA	$V_{CE} = 60\text{V}$	
H11G2			100	nA	$V_{CE} = 30\text{V}$	
H11G3			100	nA		
Coupled	Collector Output Current ( $I_C$ )				mA	$10\text{mA } I_F, 1.2\text{V } V_{CE}$
	H11G1, H11G2	100			mA	$1\text{mA } I_F, 5\text{V } V_{CE}$
	H11G1, H11G2	5			mA	$1\text{mA } I_F, 5\text{V } V_{CE}$
	H11G3	2			mA	
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$				V	$1\text{mA } I_F, 1\text{mA } I_C$
	H11G1, H11G2			1.0	V	$16\text{mA } I_F, 50\text{mA } I_C$
	H11G1, H11G2			1.2	V	$20\text{mA } I_F, 50\text{mA } I_C$
	H11G3			1.2	V	
	Input to Output Isolation Voltage $V_{ISO}$	5300			$V_{RMS}$	See note 1
		7500			$V_{PK}$	See note 1
	Input-output Isolation Resistance $R_{ISO}$	$10^{11}$			$\Omega$	$V_{IO} = 500\text{V}$ (note 1)
Input-output Capacitance $C_f$		0.5		pF	$V = 0, f = 1\text{MHz}$	
Turn-on Time $t_{on}$		5		$\mu\text{s}$	$I_F = 10\text{mA}, V_{CC} = 5\text{V},$	
Turn-off Time $t_{off}$		100		$\mu\text{s}$	$R_L = 100\Omega, f = 30\text{Hz},$	
					pulse width equal to or less than $300\mu\text{s}$	

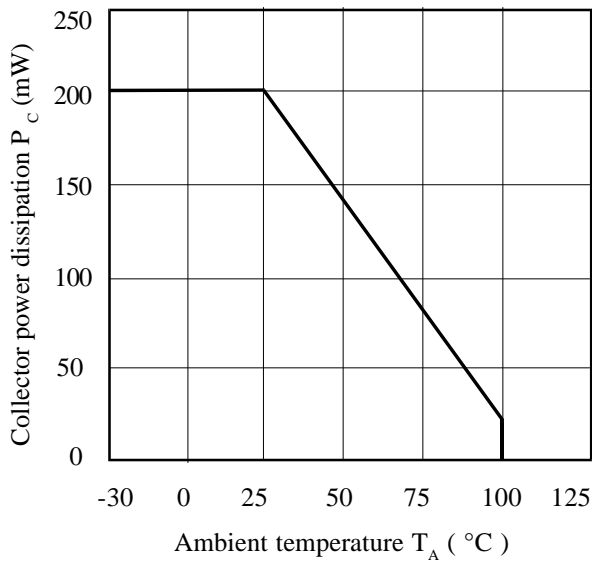
Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

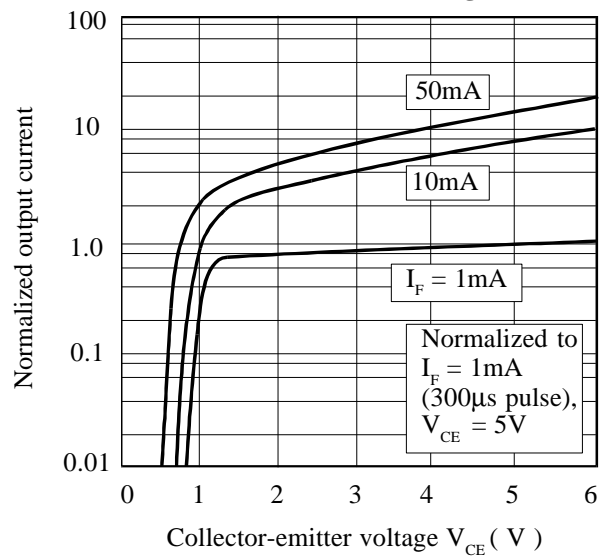
**FIGURE 1**



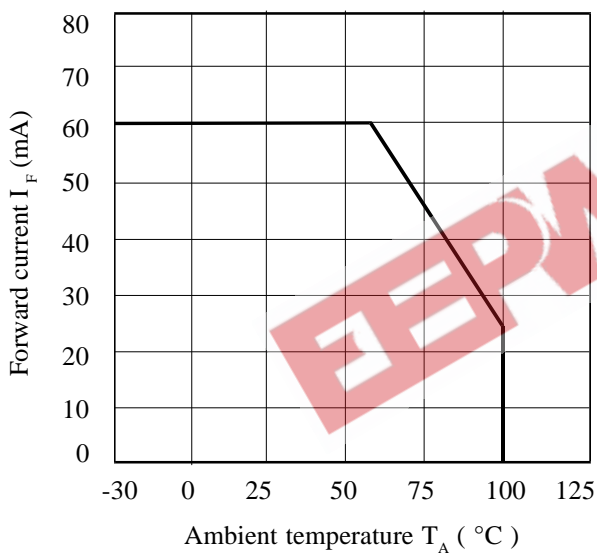
**Collector Power Dissipation vs. Ambient Temperature**



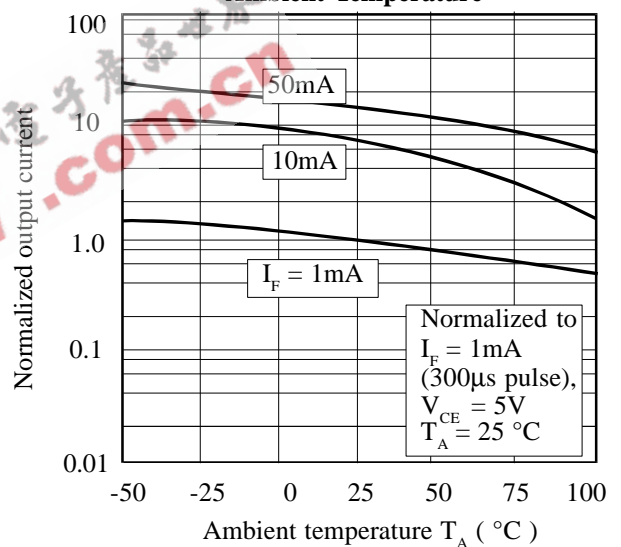
**Normalized Output Current vs. Collector-emitter Voltage**



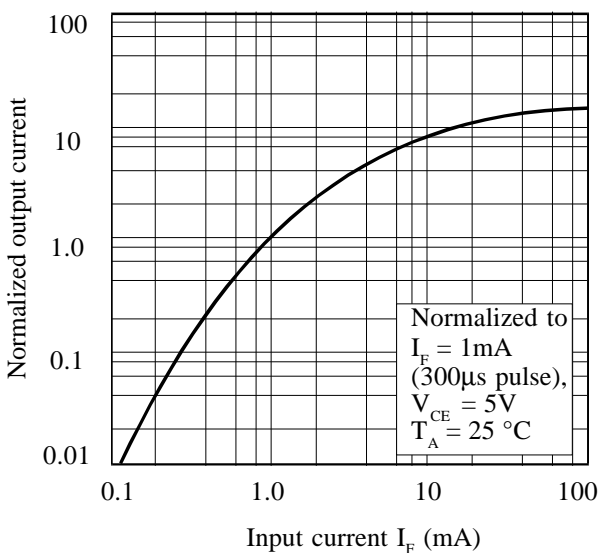
**Forward Current vs. Ambient Temperature**



**Normalized Output Current vs. Ambient Temperature**



**Normalized Output Current vs. Input Current**



**Collector Dark Current vs. Ambient Temperature**

